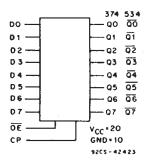


Data sheet acquired from Harris Semiconductor



# Octal D-Type Flip-Flops, 3-State

Positive-Edge Triggered

CD54/74AC/ACT374 - Non-Inverting CD54/74AC/ACT534 - Inverting

### **Type Features:**

- Buffered inputs
- Typical propagation delay:

FUNCTIONAL DIAGRAM

5 ns @  $V_{CC}$  = 5 V,  $T_A$  = 25° C,  $C_L$  = 50 pF

The RCA-CD54/74AC374 and CD54/74AC534 and the CD54/74ACT374 and CD54/74ACT534 octal D-type, 3-state, positive-edge triggered flip-flops use the RCA ADVANCED CMOS technology. The eight flip-flops enter data into their registers on the LOW-to-HIGH transition of the clock (CP). The Output Enable (OE) controls the 3-state outputs and is independent of the register operation. When the Output Enable (OE) is HIGH, the outputs are in the high-impedance state. The CD54/74AC/ACT374 and CD54/74AC/ACT534 share the same pin configurations, but the CD54/74AC/ ACT374 outputs are non-inverted while the CD54/74AC/ ACT534 devices have inverted outputs. (For flow-through pin configurations, see CD54/74AC/ACT564 and CD54/ 74AC/ACT574.)

The CD74AC/ACT374 and CD74AC/ACT534 are supplied in 20-lead dual-in-line plastic packages (E suffix) and in 20lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The CD54AC/ACT374 and CD54AC/ACT534, available in chip form (H suffix), are operable over the -55 to +125×C temperature range.

#### **Family Features:**

- Exceeds 2-kV ESD Protection MIL-STD-883. Method 3015
- SCR-Latch-up-resistant CMOS process and circuit design
- Speed of bipolar FAST\*/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply
- ± 24-mA output drive current
  - Fanout to 15 FAST\* ICs
  - Drives 50-ohm transmission lines

\*FAST is a Registered Trademark of Fairchild Semiconductor Corp.

#### **TRUTH TABLE**

	INPUTS	OUTPUTS				
			374	534		
ŌĒ	СР	Dn	Qn	Qn		
L		Н	Н	L		
L		L	L	Н		
L	L	Х	QO	QO		
Н	Х	Х	Z	Z		

H = High level (steady state)

L = Low level (steady state)

X = Don't care

= Transition from low to high level

QO = The level of Q before the indicated steady-state input conditions were established

Z = High impedance

MAXIMUM RATINGS, Absolute-Maximum Values:
DC SUPPLY-VOLTAGE (Vcc)0.5 to 6 V
DC INPUT DIODE CURRENT. $I_{IK}$ (for $V_1 < -0.5 \text{ V}$ or $V_1 > V_{CC} + 0.5 \text{ V}$ ) $\pm 20 \text{ mA}$
DC OUTPUT DIODE CURRENT. low (for $V_0 < -0.5$ V or $V_0 > V_{cc} + 0.5$ V)
DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, Io (for $V_0 > -0.5 \text{ V}$ or $V_0 < V_{CC} + 0.5 \text{ V}$ ) $\pm 50 \text{ mA}$
DC Vcc or GROUND CURRENT (Icc or IGND)
POWER DISSIPATION PER PACKAGE (P₀):
FOR $T_A = -55$ to $+100$ °C (PACKAGE TYPE E)
For $T_A = \pm 100$ to $\pm 125^{\circ}$ C (PACKAGE TYPE E) Details Linearly at 8 mW/ C to 300 mW
For T <sub>A</sub> = -55 to +70°C (PACKAGE TYPE M)
For T <sub>A</sub> = +70 to +125°C (PACKAGE TYPE M) Derate Linearly at 6 mW/°C to 70 mW
OPERATING-TEMPERATURE RANGE (T <sub>A</sub> )55 to +125°C
STORAGE TEMPERATURE (T <sub>stg</sub> )65 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance $1/16 \pm 1/32$ in. $(1.59 \pm 0.79 \text{ mm})$ from case for 10 s maximum
Unit inserted into PC board min. thickness 1/16 in. (1.59 mm) with solder contacting lead tips only +300°C
*For up to 4 outputs per device; add $\pm$ 25 mA for each additional output.

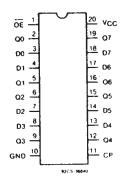
#### **RECOMMENDED OPERATING CONDITIONS:**

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

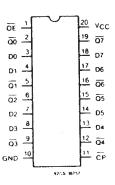
	LIM	ITS	UNITS	
CHARACTERISTIC	MIN.	MAX.	UNITS	
Supply-Voltage Range, V <sub>cc</sub> *:  (For T <sub>A</sub> = Full Package-Temperature Range)  AC Types  ACT Types	1.5 4.5	5.5 5.5	V	
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub>	0	Vcc	V	
Operating Temperature, TA	-55	+125	°C	
Input Rise and Fall Slew Rate, dt/dv at 1.5 V to 3 V (AC Types) at 3.6 V to 5.5 V (AC Types) at 4.5 V to 5.5 V (ACT Types)	0 0 0	50 20 10	ns/V ns/V ns/V	

<sup>\*</sup>Unless otherwise specified, all voltages are referenced to ground.

#### TERMINAL ASSIGNMENT DIAGRAMS



CD54/74AC/ACT374



CD54/74AC/ACT534

### STATIC ELECTRICAL CHARACTERISTICS: AC Series

		1				AMBIEN	T TEMP	RATUR	E (T <sub>A</sub> ) - °	С	
CHARACTERIST	ICS	TEST CO	NDITIONS	V <sub>cc</sub>	+	25	-40 1	o +85	-55 t	o +125	UNITS
		(V)	l <sub>o</sub> (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input				1.5	1.2	_	1.2	_	1.2	<u> </u>	
Voltage	V <sub>IH</sub>			3	2.1	_	2.1	<u> </u>	2.1		l v
				5.5	3.85	-	3.85	_	3.85	<b>1</b> –	7
Low-Level Input				1.5		0.3	T —	0.3	1 –	0.3	
Voltage	VIL			3	_	0.9	-	0.9		0.9	1 v
			l	5.5	_	1.65	_	1.65	l –	1.65	1
High-Level Output			-0.05	1.5	1.4	l –	1.4	<u> </u>	1.4	T -	
Voltage	V <sub>OH</sub>	ViH	-0.05	3	2.9		2.9		2.9	_	1
		or	-0.05	4.5	4.4		4.4		4.4		1
		VıL	-4	3	2.58	_	2.48	_	2.4		l v
			-24	4.5	3.94		3.8	_	3.7	_	1
		#, * {	-75	5.5	_		3.85	_		_	
		<b>"</b> , " {	-50	5.5	_		-		3.85		1
Low-Level Output			0.05	1.5	_	0.1		0.1		0.1	
Voltage	Vol	V <sub>IH</sub>	0.05	3	_	0.1	_	0.1	_	0.1	1
		or	0.05	4.5	_	0.1	_	0.1	_	0.1	1
		Vil	12	3	_	0.36	_	0.44	_	0.5	1 v
			24	4.5	-	0.36	_	0.44	_	0.5	
		#, * {	75	5.5	_	_		1.65		_	ĺ
		"' {	50	5.5	_	_		_	_	1.65	
Input Leakage Current	Į,	V <sub>cc</sub> or GND		5.5		±0.1	_	±1		±1	μΑ
3-State Leakage Current	loz	V <sub>IH</sub>									
ountin	102	or									
		V <sub>IL</sub>									
		$V_0 =$		5.5	- 1	±0.5	-	±5	-	±10	μΑ
		Vcc									
		or							]	ļ	
		GND									
Quiescent Supply Current, MSI	loc	V <sub>CC</sub> or GND	0	5.5	-	8		80	-	160	μΑ

<sup>#</sup>Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

\* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

Technical Data \_

# CD54/74AC374, CD54/74AC534 CD54/74ACT374, CD54/74ACT534

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

						AMBIENT	TEMPE	RATURE	(T <sub>A</sub> ) - °(	<u> </u>	<b>-</b>
CHARACTERISTI	cs	TEST CON	IDITIONS	V <sub>cc</sub>	+:	25	-40 to	o +85	-55 to +125		UNITS
		V, (V)	l <sub>o</sub> (mA)	(V)	MIN. MAX.		MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage	ViH			4.5 to 5.5	2		2		2	_	v
Low-Level Input Voltage	V <sub>IL</sub>			4.5 to 5.5	_	0.8		0.8	_	0.8	V
High-Level Output		V <sub>IH</sub>	-0.05	4.5	4.4	_	4.4		4.4		
Voltage	$V_{OH}$	or V <sub>IL</sub>	-24	4.5	3.94		3.8		3.7		V
		#, * {	-75	5.5	_		3.85				
		#, ^ {	-50	5.5		_	_		3.85		
Low-Level Output  Voltage  Vol	V <sub>IH</sub>	0.05	4.5	_	0.1		0.1		0.1		
	or V <sub>IL</sub>	24	4.5	_	0.36	_	0.44		0.5	l v	
		1 1	75	5.5			_	1.65			
		#, * {	50	5.5	_		_	_		1.65	
Input Leakage Current	~ I <sub>1</sub>	V <sub>cc</sub> or GND		5.5	_	±0.1	_	±1		±1	μΑ
3-State Leakage Current	łoz	V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = V <sub>CC</sub> or GND		5.5		±0.5		±5	_	±10	μΑ
Quiescent Supply Current, MSI	Icc	V <sub>cc</sub> or GND	0	5.5		8		80	_	160	μΑ
Additional Quiescent Current per Input P TTL Inputs High 1 Unit Load		V <sub>cc</sub> -2.1		4.5 to 5.5	_	2.4		2.8		3	mA

<sup>#</sup>Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize

### **ACT INPUT LOADING TABLE**

INPUT	UNIT LOADS*
D, ŌĒ	0.7
СР	1.17

<sup>\*</sup>Unit load is  $\Delta I_{CC}$  limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25° C.

power dissipation.

\* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

#### PREREQUISITE FOR SWITCHING: AC Series

			AMBI	ENT TEMPE	RATURE (T	A) - °C	
CHARACTERISTICS	SYMBOL	V <sub>cc</sub> (V)	-40 1	-40 to +85		+125	UNITS
		(*)	MIN.	MAX.	MIN.	MAX.	]
Clock Pulse Width	tw	1.5 3.3* 5†	44 4.9 3.5		50 5.6 4		ns
Setup Time Data to Clock	tsu	1.5 3.3 5	2 2 2	=	2 2 2		ns
Hold Time Data to Clock	t <sub>H</sub>	1.5 3.3 5	2 2 2		2 2 2	_ _ _	ns
Maximum Clock Frequency	f <sub>MAX</sub>	1.5 3.3 5	11 101 143		10 89 125		MHz

\*3.3 V: min. is @ 3 V †5 V: min. is @ 4.5 V

### SWITCHING CHARACTERISTICS: AC Series; $t_r$ , $t_t$ = 3 ns, $C_t$ = 50 pF

			AMBI	ENT TEMPE	RATURE (1	(A) - °C	
CHARACTERISTICS	SYMBOL	V <sub>cc</sub> (V)	-40 t	o +85	-55 to	+125	UNITS
		(*)	MIN.	MAX.	MIN.	MAX.	1
Propagation Delays: Clock to Q AC374	t <sub>PLH</sub>	1.5 3.3* 5†	3.9 2.8	123 13.7 9.8	— 3.8 2.7	135 15.1 10.8	ns
Clock to Q AC534	t <sub>PLH</sub> t <sub>PHL</sub>	1.5 3.3 5	 4.1 2.9	128 14.4 10.3	_ 4 2.8	141 15.8 11.3	ns
Output Enable to Q, Q	tpzL tpzH	1.5 3.3 5	5.6 3.7	165 19.8 13.2	 5.5 3.6	181 21.8 14.5	ns
Output Disable to Q, Q	t <sub>PLZ</sub>	1.5 3.3 5	4.7 3.7	165 16.5 13.2	4.5 3.6	181 18.1 14.5	ns
Power Dissipation Capacitance	Ceo§	_	67	Гур.	67	Гур.	pF
Min. (Valley) V <sub>OH</sub> During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>онv</sub> See Fig. 1	5	4 Typ. @ 25°C			V	
Max. (Peak) Vol During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>OLP</sub> See Fig. 1	5		1 Тур. (	@ 25°C		٧
Input Capacitance	Cı	_		10		10	pF
3-State Output Capacitance	Co		_	15	_	15	pF

\*3.3 V: min. is @ 3.6 V

max. is @ 3 V

†5 V: min. is @ 5.5 V

max. is @ 4.5 V

§C<sub>PD</sub> is used to determine the dynamic power consumption, per flip flop.

 $P_D = C_{PD} V_{CC}^2 f_i + \Sigma V_{CC}^2 f_0 C_L$  where  $f_i = input frequency$ 

fo = output frequency

C<sub>L</sub> = output load capacitance V<sub>cc</sub> = supply voltage.

PREREQUISITE FOR SWITCHING: ACT Series

-		14	AMBII	AMBIENT TEMPERATURE (TA) - °C					
CHARACTERISTICS	SYMBOL	MBOL V <sub>cc</sub>		-40 to +85		-55 to +125			
		(*)	MIN.	MAX.	- MIN.	MAX.			
Clock Pulse Width	t <sub>w</sub>	5†	3.9	_	4.5	_	. ns		
Setup Time Data to Clock	tsu	5	2	<u> </u>	2	_	ns		
Hold Time Data to Clock	t <sub>H</sub>	5	2.6	_	3	_	ns		
Maximum Clock Frequency	f <sub>MAX</sub>	5	125	_	110	_	MHz		

15 V: min. is @ 4.5 V

### SWITCHING CHARACTERISTICS: ACT Series; t,, t, = 3 ns, C, = 50 pF

			AMBI	ENT TEMPE	RATURE (T	(A) - °C		
CHARACTERISTICS	SYMBOL	V <sub>CC</sub>	-40 to +85		-55 to +125		UNITS	
	STMBOL (V)		MIN.	MAX.	MIN.	MAX.	1	
Propagation Delays: Clock to Q ACT374	tегн. tенг	5†	2.9	10.2	2.8	11.2	ns	
Clock to Q ACT534	t <sub>PLH</sub>	5	3	10.6	2.9	11.7	ns	
Output Enable and Disable to Q ACT374	tplz tpHz tpZL tpZH	5	3.7	13.2	3.6	14.5	ns	
Output Enable and Disable to Q ACT534	tplz tpHz tpZL tpZH	5	3.7	13.2	3.6	14.5	ns	
Power Dissipation Capacitance	C <sub>PD</sub> §		67	Тур.	67	Тур.	pF	
Min. (Valley) V <sub>он</sub> During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>онv</sub> See Fig. 1	5	4 Typ. @ 25°C			V		
Max. (Peak) Vol. During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>OLP</sub> See Fig. 1	5		1 Typ. (	@ 25°C		v	
Input Capacitance	Ci	-		10	_	10	ρF	
3-State Output Capacitance	Co	_	_	15	_	15	pF	

†5 V: min. is @ 5.5 V max. is @ 4.5 V

§C<sub>PD</sub> is used to determine the dynamic power consumption, per flip flop.

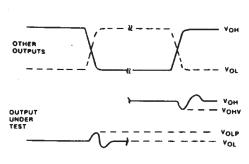
 $P_D = C_{PD} V_{CC}^2 f_i + V_{CC}^2 f_0 C_L + V_{CC} \Delta I_{CC}$  where  $f_i = input$  frequency

 $f_0 = output$  frequency

C<sub>L</sub> = output load capacitance

 $V_{CC}$  = supply voltage.

### PARAMETER MEASUREMENT INFORMATION



#### NOTES:

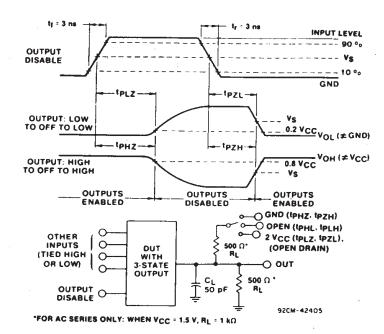
- NOTES:

  1. YOMY AND YOLP ARE MEASURED WITH RESPECT TO A GROUND REFERENCE NEAR THE OUTPUT UNDER TEST.

  2. INPUT PULSES MAVE THE FOLLOWING CHARACTERISTICS: PAR < 1 MHA. 1, -1 an. 1, -1 an. 5 KEW 1 ns.

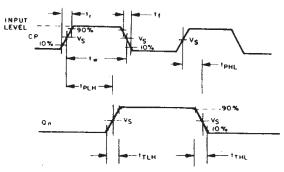
  3. R.F. FIXTURE WITH 700-MHz DESIGN RULES REQUIRED. IC SHOULD BE SOLDERED INTO TEST BOARD AND BYPASSED WITH 0.1 IF CAPACITOR. SCOPE AND PROBES REQUIRE 700-MHz BANDWIDTH.

9205-42406

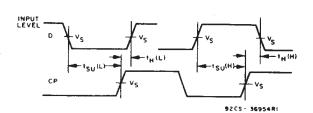


\*For AC series only: When  $V_{CC}$  = 1.5V,  $R_L$  = 1 k $\Omega$ 

Fig. 1 - Simultaneous switching transient waveforms. Fig. 2 - Three-state propagation delay waveforms and test circuit.



92 CS - 38404 RI



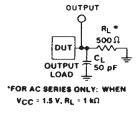


Fig. 3 - Propagation delay times and test circuit.

	CD54/74AC	<b>CD54/74ACT</b>
Input Level	V <sub>cc</sub>	3 V
Input Switching Voltage, Vs	0.5 V <sub>cc</sub>	1.5 V
Output Switching Voltage, Vs	0.5 V <sub>cc</sub>	0.5 V <sub>cc</sub>

#### PACKAGE OPTION ADDENDUM



i.com 26-Sep-2005

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CD54AC374F3A	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
CD54ACT374F3A	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
CD54ACT534F3A	OBSOLETE	CDIP	J	20		TBD	Call TI	Call TI
CD74AC374E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74AC374EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74AC374M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC374M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC374M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC374ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC534M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC534M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74ACT374M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the



### **PACKAGE OPTION ADDENDUM**

26-Sep-2005

accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

### 14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## N (R-PDIP-T\*\*)

### PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



# DW (R-PDSO-G20)

### PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



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Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

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